## NSN 5961-00-501-0656

**Fiig:** A110a0

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Function For Which Designed:	
Amplifier	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
To-71	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Clip and terminal	
Terminal Circle Diameter:	
Between 0.095 inches and 0.105 inches	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
60.0 breakdown voltage, collector-to-emitter, base open all transistor and 60.0 collector to base voltage, dc all transistor and	6.0 emitte
to base, rms all transistor	
Current Rating Per Characteristic:	
30.00 milliamperes source cutoff current all transistor	
Power Rating Per Characteristic:	
300.0 milliwatts small-signal input power, common-collector absolute all transistor	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
All transistor junction pattern arrangement: npn	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	